

S8NC

#### 8.0A SURFACE MOUNT GLASS PASSIVATED RECTIFIER

## **Product Summary** @T<sub>A</sub> = +25°C

| V <sub>RRM</sub> (V) | lo (A) | V <sub>F</sub> (V) | I <sub>R</sub> (μΑ) |
|----------------------|--------|--------------------|---------------------|
| 1200                 | 8      | 1.1                | 10                  |

## **Description and Applications**

8.0A Surface Mount Glass Passivated Rectifier in SMC package, offers high current capability and low forward voltage drop, designed with guard ring for transient protection and high surge capacity.

Power Supplies

## **Features and Benefits**

- Glass Passivated Die Construction
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 225A Peak
- High Reverse Breakdown Voltage of 1200V
- Lead-Free Finish/RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Mechanical Data**

- Case: SMC
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Alloy Leadframe. Solderable per MIL-STD-202, Method 208 ()
- Polarity: Cathode Band
- Weight: 0.26 grams (Approximate)



Top View



Bottom View

## Ordering Information (Note 4)

| Part Number | Case | Packaging         |
|-------------|------|-------------------|
| S8NC-13     | SMC  | 3,000/Tape & Reel |

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

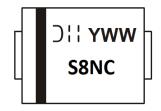
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

Notes:



S8NC = Product Type Marking Code Cartering State Stat



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

| For | ca | pacita | nce le | oad, | derate | current by | 20%. |
|-----|----|--------|--------|------|--------|------------|------|

| Characteristic   |                          | Symbol                                     | Value | Unit |
|--|--------------------------|--|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage |                          | V <sub>RRM</sub><br>V <sub>RWM</sub><br>Vr | 1200  | V    |
| RMS Reverse Voltage  |                          | V <sub>R(RMS)</sub>                        | 850   | V    |
| Average Rectified Output Current   | @ T <sub>T</sub> = +25°C | lo   | 8.0   | А    |
| Non-Repetitive Peak Forward Surge Cu<br>Single Half Sine-Wave Superimposed of          |                          | IFSM                                       | 225   | А    |

### **Thermal Characteristics**

Notes:

| Characteristic  | Symbol           | Value       | Unit |
|---|------------------|-------------|------|
| Typical Thermal Resistance, Junction to Terminal (Note 5) | R <sub>θJT</sub> | 10.4        | °C/W |
| Operating and Storage Temperature Range                   | $T_{J,} T_{STG}$ | -65 to +150 | °C   |

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

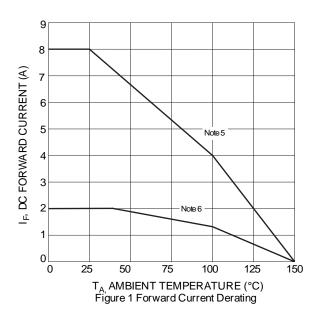
| Characteristic                     | Symbol             | Min  | Тур           | Max        | Unit | Test Condition  |
|------------------------------------|--------------------|------|---------------|------------|------|---|
| Reverse Breakdown Voltage (Note 7) | V <sub>(BR)R</sub> | 1200 | —             | —          | V    | I <sub>R</sub> = 10μA   |
| Forward Voltage                    | VF                 | _    | 0.98<br>0.885 | 1.1<br>1.0 | V    | I <sub>F</sub> = 8.0A, T <sub>A</sub> = +25°C<br>I <sub>F</sub> = 8.0A, T <sub>A</sub> = +125°C |
| Leakage Current (Note 7)           | I <sub>R</sub>     |      | 0.22<br>20    | 10<br>500  | μA   | V <sub>R</sub> =1200V, T <sub>A</sub> = +25°C<br>V <sub>R</sub> =1200V, T <sub>A</sub> = +125°C |
| Total Capacitance (Note 8)         | CT                 |      | 40            | _          | pF   | $V_{R} = 4V, f = 1.0MHz$  |

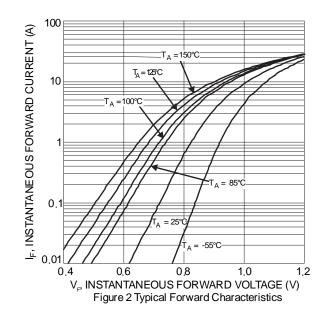
5. The device has two heat sinks of size 20mm \* 70mm attached to each terminal (i.e. four heat sinks total).

6. Device mounted on FR-4 substrate, 0.4in. \* 0.5in. 2oz single-sided, PC board with 0.2in. \* 0.25in. copper pads.

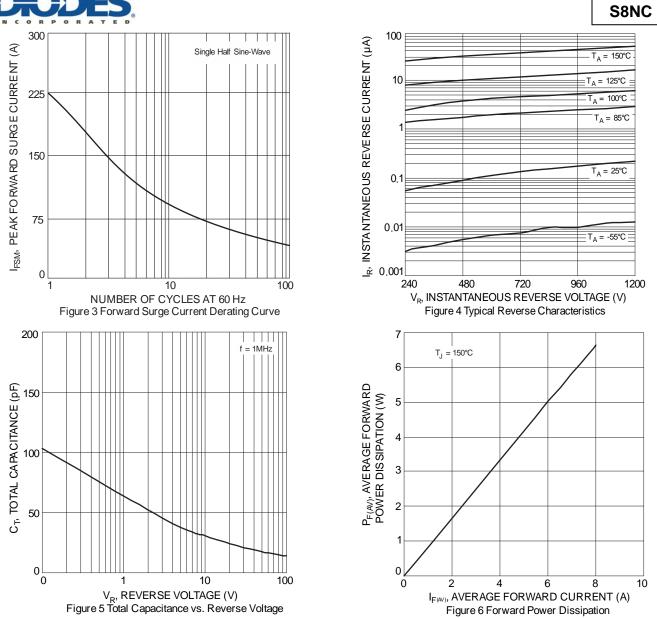
7. Short duration pulse test used to minimize self-heating effect.

8. Measured at f = 1.0MHz and applied reverse voltage of VR=4.0V DC.



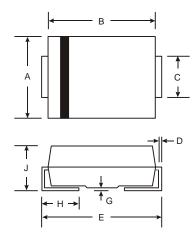






# Package Outline Dimensions

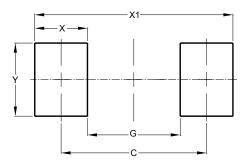
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



|                      | SMC  |      |  |  |
|----------------------|------|------|--|--|
| Dim                  | Min  | Max  |  |  |
| Α                    | 5.59 | 6.22 |  |  |
| В                    | 6.60 | 7.11 |  |  |
| С                    | 2.75 | 3.18 |  |  |
| D                    | 0.15 | 0.31 |  |  |
| Е                    | 7.75 | 8.13 |  |  |
| G                    | 0.10 | 0.20 |  |  |
| Н                    | 0.76 | 1.52 |  |  |
| J                    | 2.00 | 2.50 |  |  |
| All Dimensions in mm |      |      |  |  |



Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С          | 6.90          |
| G          | 4.40          |
| Х          | 2.50          |
| X1         | 9.40          |
| Y          | 3.30          |

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